35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

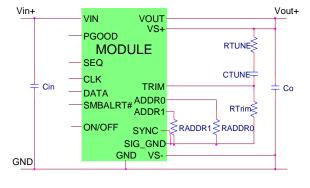
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current



RoHS Compliant

Applications

- Distributed power architectures
- Intermediate bus voltage applications
- Telecommunications equipment
- Servers and storage applications
- Networking equipment
- Industrial equipment



Features

- Compliant to RoHS II EU "Directive 2011/65/EU"
- Compatible in a Pb-free or SnPb reflow environment (Z versions)
- Compliant to IPC- 9592 (September 2008), Category 2, Class I
- Compliant to REACH Directive (EC) No 1907/2006
- DOSA based
- Wide Input voltage range (4.5Vdc-14.4Vdc)
- Output voltage programmable from 0.51Vdc to 3.63Vdc via external resistor and PMBus™#
- Digital interface through the PMBus^{™#} protocol
- Tunable Loop™ to optimize dynamic output voltage response
- Flexible output voltage sequencing EZ-SEQUENCE
- Power Good signal
- Fixed switching frequency with capability of external synchronization
- Output over current protection (non-latching)
- Over temperature protection
- Remote On/Off
- Ability to sink and source current
- Cost efficient open frame design
- Small size: 20.32 mm x 11.45 mm x 11 mm (0.8 in x 0.45 in x 0.433 in)
- Wide operating temperature range [-40°C to 85°C]
- UL* 60950-1 2nd Ed. Recognized, CSA[†] C22.2 No. 60950-1-07 Certified, and VDE[‡] (EN60950-1 2nd Ed.) Licensed
- ISO** 9001 and ISO 14001 certified manufacturing facilities

Description

The 35A Digital MicroDLynxIITM power modules are non-isolated dc-dc converters that can deliver up to 35A of output current. These modules operate over a wide range of input voltage ($V_{IN} = 4.5 \text{Vdc}-14.4 \text{Vdc}$) and provide a precisely regulated output voltage from 0.51Vdc to 3.63Vdc, programmable via an external resistor and PMBusTM control. Features include a digital interface using the PMBusTM protocol, remote On/Off, adjustable output voltage, over current and over temperature protection. The PMBus^{TM#} interface supports a range of commands to both control and monitor the module. The module also includes the Tunable LoopTM feature that allows the user to optimize the dynamic response of the converter to match the load with reduced amount of output capacitance leading to savings on cost and PWB area.

- * UL is a registered trademark of Underwriters Laboratories, Inc.
- † CSA is a registered trademark of Canadian Standards Association.
- VDE is a trademark of Verband Deutscher Elektrotechniker e.V.
- ** ISO is a registered trademark of the International Organization of Standards
- # The PMBus name and logo are registered trademarks of the System Management Interface Forum (SMIF)



35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage	All	V _{IN}	-0.3	15	V
Continuous					
VS, ON/OFF, SEQ	All			7	V
CLK, DATA, SMBALERT#,SYNC	All		-0.3	3.6	V
Operating Ambient Temperature	All	TA	-40	85	°C
(see Thermal Considerations section)					
Storage Temperature	All	T_{stg}	-55	125	°C

Electrical Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Operating Input Voltage	All	V _{IN}	4.5		14.4	Vdc
Maximum Input Current	All	I _{IN,max}			33	Adc
$(V_{IN}=4.5V \text{ to } 14V, I_{O}=I_{O, max})$						
Input No Load Current	V _{O,set} = 0.6 Vdc	I _{IN,No load}		43		mA
$(V_{IN} = 12Vdc, I_0 = 0, module enabled)$	$V_{0,set} = 3.63Vdc$	I _{IN,No} load		106		mA
Input Stand-by Current $(V_{IN} = 12Vdc, module disabled)$	All	I _{IN} ,stand-by		16		mA
Inrush Transient	All	2 †			1	A ² s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, 1µH source impedance; V _{IN} =0 to 14V, I ₀ = I _{0max} ; See Test Configurations)	All	1-0		35	1	mAp-p
Input Ripple Rejection (120Hz)	All			-71		dB
Output Voltage Set-point (with 0.1% tolerance for RTrim)						
0 to 85°C, Vo=0.6V	All	VO, set	-1.53		+1.53	% VO, set
Vo=1.2V	All	VO, set	-1.37		+1.37	% VO, set
Vo=3.3V	All	VO, set	-1.22		+1.22	% VO, set
-40 to 85°C, Vo=0.6V	All	VO, set	-2.03		+2.03	% VO, set
Vo=1.2V	All	VO, set	-1.87		+1.87	% VO, set
Vo=3.3V	All	VO, set	-1.72		+1.72	% VO, set
Output Voltages (Over all operating input voltage, resistive load, until end of life)						
0 to 85°C, Vo=0.6V	All	VO, set	-1.83		+1.83	% VO, set
Vo=1.2V	All	VO, set	-1.67		+1.67	% VO, set
Vo=3.3V	All	VO, set	-1.52		+1.52	% VO, set
-40 to 85°C, Vo=0.6V	All	VO, set	-2.33		+2.33	% VO, set
Vo=1.2V	All	VO, set	-2.17		+2.17	% VO, set
Vo=3.3V	All	VO, set	-2.02		+2.02	% VO, set

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Electrical Specifications (continued)

Parameter	Device	Symbo	Min	Тур	Max	Unit
Adjustment Range (selected by an external resistor) (Some output voltages may not be possible depending on the input voltage – see Feature Descriptions Section)	All	Vo	0.6		3.63	Vdc
PMBus Adjustable Output Voltage Range	All	V ₀ ,adj	-15	0	+10	%V _{O,set}
PMBus Output Voltage Adjustment Step Size	All			0.4		%V _{O,set}
Remote Sense Range	All				0.5	Vdc
Output Regulation (for V ₀ ≥ 2.5Vdc)						
Line (V _{IN} =V _{IN, min} to V _{IN, max})	All				±0.15	% V _{O, set}
Load ($I_0=I_{0, min}$ to $I_{0, max}$)	All				6	mV
Output Regulation (for $V_0 < 2.5Vdc$)						
Line ($V_{IN}=V_{IN,min}$ to $V_{IN,max}$)	All				5	mV
Load ($I_0=I_0$, min to I_0 , max)	All				5	mV
Temperature ($T_{ref}=T_{A, min}$ to $T_{A, max}$)	All				0.4	$\% V_{O, set}$
Output Ripple and Noise on nominal output ($V_{IN}=V_{IN,nom}$ and $I_{O}=I_{O,min}$ to $I_{O,max}$ Co = $0.1\mu F$ // $8x47~\mu F$ ceramic capacitors)						
Peak-to-Peak (5Hz to 20MHz bandwidth)	All			17		mV_{pk-pk}
RMS (5Hz to 20MHz bandwidth)	All			3.2		mV_{rms}
External Capacitance ¹						
Without the Tunable Loop™						
ESR ≥ 1 mΩ	All	C _{O, max}	8x47		16×47	μF
With the Tunable Loop $^{\text{TM}}$						
ESR ≥ 0.15 mΩ	All	C _{O, max}	8x47		7000	μF
ESR ≥ 10 mΩ	All	C _{O, max}	8x47		8500	μF
Output Current (in either sink or source mode)	All	lo	0		35 ²	Adc
Output Current Limit Inception (Hiccup Mode) (current limit does not operate in sink mode)	All	I _{O, lim}		412		Adcmax
Output Short-Circuit Current	All	I _{O, s/c}		18		Arms
(V _o ≤250mV) (Hiccup Mode)						
Efficiency	V _{O,set} = 0.6Vdc	η		80.2%		%
V _{IN} = 12Vdc, T _A =25°C	V _{O, set} = 1.2Vdc	η		87.8%		%
$I_O=I_{O,max}$, $V_O=V_{O,set}$	V _{O,set} = 1.8Vdc	η		91.4%		%
	V _{O,set} = 2.5Vdc	η		93.2%		%
	$V_{O,set} = 3.3Vdc$	η		94.3%		%
Switching Frequency	All	f_{sw}		500		kHz

¹External capacitors may require using the new Tunable Loop™ feature to ensure that the module is stable as well as getting the best transient response. See the Tunable Loop™ section for details.

 $^{^2}$ For ambient temperatures lower that -20C the minimum OCP is 30A. Monotonic start-up is guaranteed for output current 30A and below.

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Electrical Specifications (continued)

Parameter	Device	Symbol	Min	Тур	Max	Unit
Frequency Synchronization	All					
Synchronization Frequency Range (2 × f _{switch})	All		950	1000	1050	kHz
High-Level Input Voltage	All	V _{IH}	2			V
Low-Level Input Voltage	All	VIL			0.4	V
Minimum Pulse Width, SYNC	All	t _{sync}	100			ns
Maximum SYNC rise time	All	t _{sync_sh}			100	ns

General Specifications

Parameter	Device	Min	Тур	Max	Unit
Calculated MTBF (I ₀ =0.8I _{0, max} , T _A =40°C) Telecordia Issue 2 Method 1 Case 3	All		66,823,110		Hours
Weight			7.3		g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply overall operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Тур	Max	Unit
On/Off Signal Interface						
($V_{IN} \! = \! V_{IN, min}$ to $V_{IN, max}$; open collector or equivalent,						
Signal referenced to GND)						
Device code with suffix "4" – Positive Logic (See Ordering Information)						
Logic High (Module ON)						
Input High Current	All	Іін			17	uA
Input High Voltage	All	VIH	2.1		7	V
Logic Low (Module OFF)						
Input Low Current	All	lıL			2	uA
Input Low Voltage	All	VIL	-0.2		0.8	V
Device Code with no suffix – Negative Logic (See Ordering Information)						
(On/OFF pin is open collector/drain logic input with						
external pull-up resistor; signal referenced to GND)						
Logic High (Module OFF)						
Input High Current	All	Іін			3	mA
Input High Voltage	All	VIH	2.1		7	Vdc
Logic Low (Module ON)						
Input low Current	All	lıL			500	μΑ
Input Low Voltage	All	VIL	0		0.8	Vdc

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Feature Specifications (cont.)

Parameter	Device	Symbol	Min	Тур	Max	Units
Turn-On Delay and Rise Times						
$(V_{IN}=V_{IN, nom,} I_0=I_{0, max}, V_0 \text{ to within } \pm 1\% \text{ of steady state})$						
Case 1: On/Off input is enabled and then input power is applied (delay from instant at which $V_{IN} = V_{IN, min}$ until $V_0 = 10\%$ of V_0 , set)	All	Tdelay		1.2		msec
Case 2: Input power is applied for at least one second and then the On/Off input is enabled (delay from instant at which Von/Off is enabled until Vo = 10% of Vo, set)	All	Tdelay		1.1		msec
Output voltage Rise time (time for V ₀ to rise from 10% of V ₀ , set to 90% of V ₀ , set)	All	Trise		2.7		msec
Output voltage overshoot ($T_A = 25^{\circ}C$) $V_{IN} = V_{IN, min}$ to $V_{IN, max, lo} = I_{O, min}$ to $I_{O, max}$) With or without maximum external capacitance					3.0	% V _{O, set}
Over Temperature Protection (See Thermal Considerations section)	All	Тот		122		°C
PMBus Over Temperature Warning Threshold *	All	Twarn		105		°C
Tracking Accuracy (Power-Up: 2V/ms)	All	VSEQ -Vo			100	mV
(Power-Down: 2V/ms)	All	VSEQ -Vo			200	mV
$(V_{IN, min} to V_{IN, max}; I_{O, min} to I_{O, max} OV < VSEQ < V_O)$						
Input Undervoltage Lockout						
Turn-on Threshold	All			4.25		Vdc
Turn-off Threshold	All			4.05		Vdc
Hysteresis	All			0.2		Vdc
PMBus Adjustable Input Under Voltage Lockout Thresholds	All		4		14	Vdc
Resolution of Adjustable Input Under Voltage Threshold	All		250			mV
PGOOD (Power Good)						
Signal Interface Open Drain, V _{supply} ≤ 5VDC						
Overvoltage threshold for PGOOD ON	All			108.33		$%V_{O, set}$
Overvoltage threshold for PGOOD OFF	All			112.5		$%V_{O,set}$
Undervoltage threshold for PGOOD ON	All			91.67		$\%V_{O,set}$
Undervoltage threshold for PGOOD OFF	All			87.5		$\%V_{O,set}$
Pulldown resistance of PGOOD pin	All			40	70	Ω
Sink current capability into PGOOD pin	All				5	mA

^{*} Over temperature Warning – Warning may not activate before alarm and unit may shutdown before warning

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Digital Interface Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

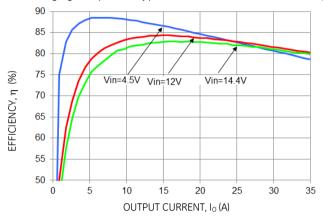
Parameter	Conditions	Symbol	Min	Тур	Max	Unit	
PMBus Signal Interface Characteristics							
Input High Voltage (CLK, DATA)		VIH	2.1		3.6	V	
Input Low Voltage (CLK, DATA)		VIL			0.8	V	
Input high level current (CLK, DATA)		Іін	-10		10	μΑ	
Input low level current (CLK, DATA)		I _{IL}	-10		10	μΑ	
Output Low Voltage (CLK, DATA, SMBALERT#)	I _{OUT} =2mA	Vol			0.4	V	
Output high level open drain leakage current (DATA, SMBALERT#)	V _{OUT} =3.6V	Іон	0		10	μΑ	
Pin capacitance		Со		0.7		pF	
PMBus Operating frequency range	Slave Mode	Fрмв	10		400	kHz	
Data hold time	Receive Mode Transmit Mode	thd:dat	300			ns	
Data setup time		tsu:dat	250			ns	
Measurement System Characteristics							
Output current measurement range		I _{RNG}	0		50	А	
Output current measurement accuracy -40 to 85°C		I _{ACC}	-7		5	%	
Temperature measurement accuracy @12Vin, 0°C to 85°C		Tacc		±10		°C	
V _{OUT} measurement range		V _{OUT(rng)}	0		4	V	
V _{OUT} measurement accuracy		Vout, acc	-2		2	%	

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII™ at 0.6Vo and 25°C.



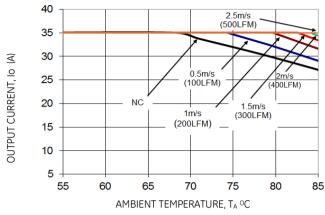
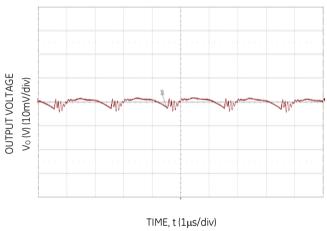


Figure 1. Converter Efficiency versus Output Current.

Figure 2. Derating Output Current versus Ambient Temperature and Airflow.



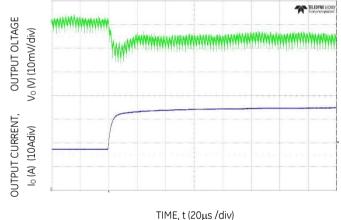
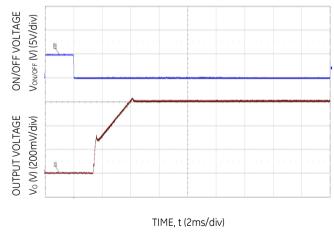


Figure 3. Typical output ripple (Co=8x47 μ F ceramic, ViN = 12V, Io = Io,max,).

Figure 4. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+24x330uF, CTune=18nF, RTune=300 Ω



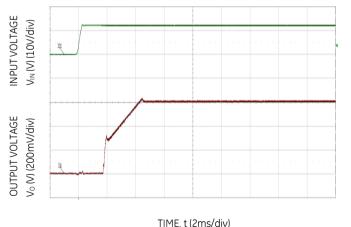


Figure 5. Typical Start-up Using On/Off Voltage ($I_0 = I_{0,max}$).

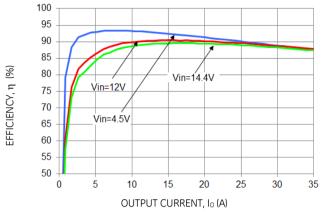
Figure 6. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{0,max}$).

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII™ at 1.2Vo and 25°C.



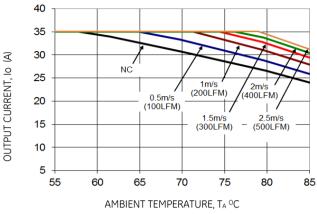
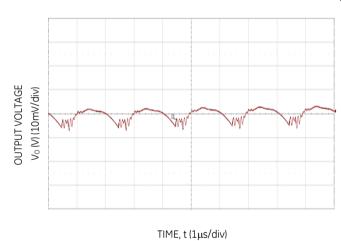


Figure 7. Converter Efficiency versus Output Current.

Figure 8. Derating Output Current versus Ambient Temperature and Airflow.



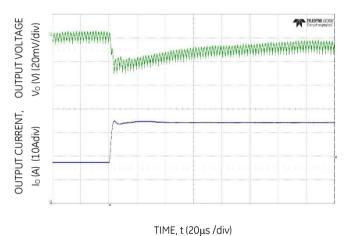


Figure 9. Typical output ripple ($C_0=8x47\mu F$ ceramic, $V_{IN}=12V$, $I_0=I_{0.max}$.).

Figure 10. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+14x330uF, CTune=10nF, RTune=300 Ω

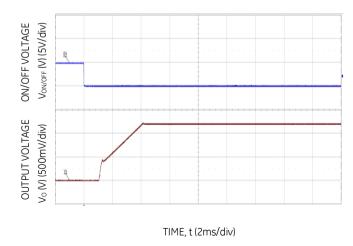




Figure 11. Typical Start-up Using On/Off Voltage (Io = Io,max).

Figure 12. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{O, max}$).

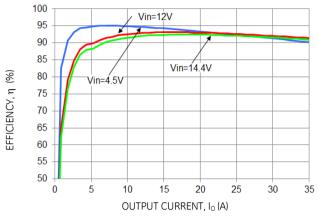
TIME, t (2ms/div)

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII™ at 1.8Vo and 25°C.



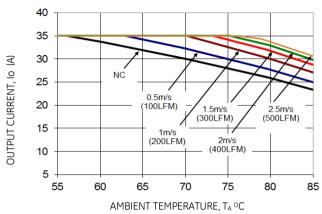
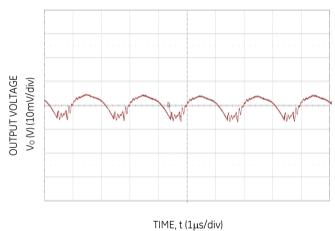


Figure 13. Converter Efficiency versus Output Current.

Figure 14. Derating Output Current versus Ambient Temperature and Airflow.



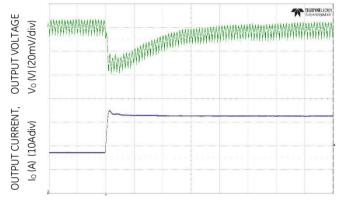
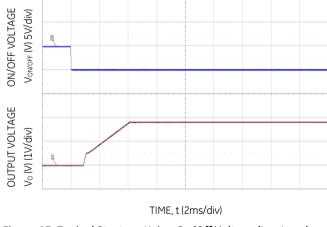


Figure 15. Typical output ripple and noise ($C_0=8x47\mu F$ ceramic, $V_{IN}=12V$, $I_0=I_{0,max}$,).

Figure 16. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+7x330uF, CTune=4.7nF, RTune=221 Ω

TIME, t (20µs /div)



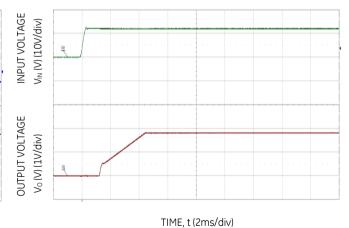


Figure 17. Typical Start-up Using On/Off Voltage ($I_0 = I_{0,max}$).

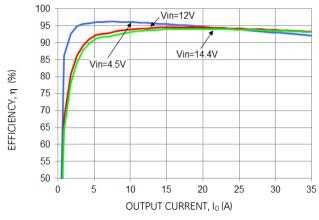
Figure 18. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{0,max}$).

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Characteristic Curves

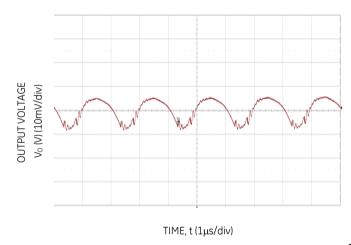
The following figures provide typical characteristics for the 35A Digital MicroDLynxII™ at 2.5Vo and 25°C.



40 35 30 <u> 2</u> OUTPUT CURRENT, Io 1m/s (200LFM) 25 0.5m/s 20 2.5m/s (500LFM) 15 (400LFM) 10 1.5 m/s(300LFM) 5 55 85 AMBIENT TEMPERATURE, TA °C

Figure 19. Converter Efficiency versus Output Current.

Figure 20. Derating Output Current versus Ambient Temperature and Airflow.



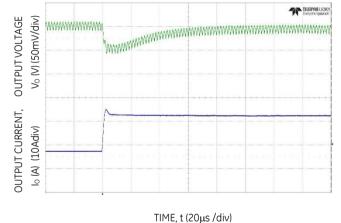
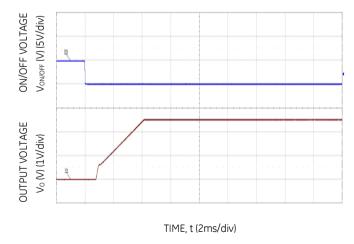


Figure 21. Typical output ripple and noise (Co=8x47µF ceramic, V_{IN} = 12V, I_0 = $I_{0,max}$,).

Figure 22. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+4x330uF, CTune=3300pF, RTune=221 Ω



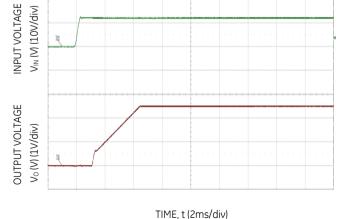


Figure 23. Typical Start-up Using On/Off Voltage (Io = Io,max).

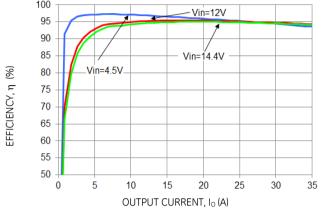
Figure 24. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{O,max}$).

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Characteristic Curves

The following figures provide typical characteristics for the 35A Digital MicroDLynxII™ at 3.3Vo and 25°C.



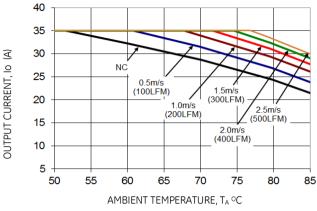
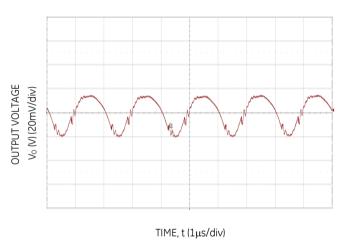


Figure 25. Converter Efficiency versus Output Current.

Figure 26. Derating Output Current versus Ambient Temperature and Airflow.



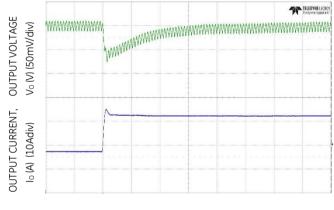
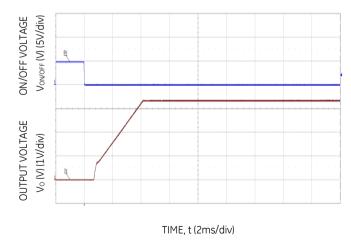


Figure 27. Typical output ripple and noise ($C_0=7x22\mu F$ ceramic, $V_{IN}=12V$, $I_0=I_{0,max}$,).

Figure 28 Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout=8x47uF+2x330uF, CTune=2700pF, RTune=221 Ω

TIME, t (20µs /div)



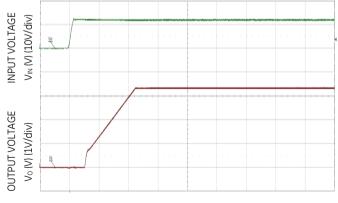


Figure 29. Typical Start-up Using On/Off Voltage (Io = Io, max).

Figure 30. Typical Start-up Using Input Voltage ($V_{IN}=12V$, $I_0=I_{0,max}$).

TIME, t (2ms/div)

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Design Considerations

Input Filtering

The 35A Digital MicroDLynxII $^{\text{TM}}$ module should be connected to a low ac-impedance source. A highly inductive source can affect the stability of the module. An input capacitance must be placed directly adjacent to the input pin of the module, to minimize input ripple voltage and ensure module stability.

To minimize input voltage ripple, ceramic capacitors are recommended at the input of the module. Figure 31 shows the input ripple voltage for various output voltages at 35A of load current with 4x22 μ F, 6x22 μ F or 8x22 μ F ceramic capacitors and an input of 12V.

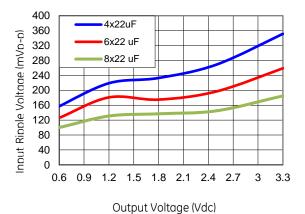


Figure 31. Input ripple voltage for various output voltages with 4x22 μ F, 6x22 μ F or 8x22 μ F ceramic capacitors at the input (35A load). Input voltage is 12V.

Output Filtering

These modules are designed for low output ripple voltage and will meet the maximum output ripple specification with 0.1 μF ceramic and 2x47 μF ceramic capacitors at the output of the module. However, additional output filtering may be required by the system designer for a number of reasons. First, there may be a need to further reduce the output ripple and noise of the module. Second, the dynamic response characteristics may need to be customized to a particular load step change.

To reduce the output ripple and improve the dynamic response to a step load change, additional capacitance at the output can be used. Low ESR polymer and ceramic capacitors are recommended to improve the dynamic response of the module. Figure 32 provides output ripple information for different external capacitance values at various Vo and a full load current of 35A. For stable operation of the module, limit the capacitance to less than the maximum output capacitance as specified in the electrical specification table. Optimal performance of the module can be achieved by using the Tunable Loop $^{\text{TM}}$ feature described later in this data sheet.

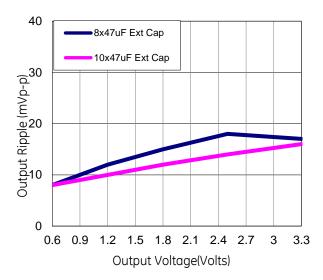


Figure 32. Output ripple voltage for various output voltages with external 4x47 μ F, 6x47 μ F or 8x47 μ F ceramic capacitors at the output (35A load). Input voltage is 12V.

Safety Considerations

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., UL 60950-1 2nd, CSA C22.2 No. 60950-1-07, DIN EN 60950-1:2006 + A11 (VDE0805 Teil 1 + A11):2009-11; EN 60950-1:2006 + A11:2009-03.

For the converter output to be considered meeting the requirements of safety extra-low voltage (SELV), the input must meet SELV requirements. The power module has extra-low voltage (ELV) outputs when all inputs are ELV. An external 40A 461 series Littelfuse fuse model or equivalent is recommended on the ungrounded input lead when the input voltage exceeds 8V. For input voltages less than 8V, 2 parallel 25A 456 series Littelfuse or equivalent are recommended on the ungrounded input lead.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Analog Feature Descriptions

Remote On/Off

The module can be turned ON and OFF either by using the ON/OFF pin (Analog interface) or through the PMBus interface (Digital). The module can be configured in a number of ways through the PMBus interface to react to the two ON/OFF inputs:

- Module ON/OFF can be controlled only through the analog interface (digital interface ON/OFF commands are ignored)
- Module ON/OFF can be controlled only through the PMBus interface (analog interface is ignored)
- Module ON/OFF can be controlled by either the analog or digital interface

The default state of the module (as shipped from the factory) is to be controlled by the analog interface only. If the digital interface is to be enabled, or the module is to be controlled only through the digital interface, this change must be made through the PMBus. These changes can be made and written to non-volatile memory on the module so that it is remembered for subsequent use.

Analog On/Off

The 35A Digital MicroDLynxIITM power modules feature an On/Off pin for remote On/Off operation. Two On/Off logic options are available. In the Positive Logic On/Off option, (device code suffix "4" – see Ordering Information), the module turns ON during a logic High on the On/Off pin and turns OFF during a logic Low. With the Negative Logic On/Off option, (no device code suffix, see Ordering Information), the module turns OFF during logic High and ON during logic Low. The On/Off signal should be always referenced to ground. For either On/Off logic option, leaving the On/Off pin disconnected will turn the module ON when input voltage is present.

For positive logic modules, the circuit configuration for using the On/Off pin is shown in Figure 33. When the external transistor Q1 is in the OFF state, the internal PWM #Enable is pulled up internally, thus turning the module ON. When transistor Q1 is turned ON, the On/Off pin is pulled low, and consequently the internal PWM Enable signal is pulled low and the module is OFF.

For negative logic On/Off modules, the circuit configuration is shown in Fig. 34. The On/Off pin should be pulled high with an external pull-up resistor. When transistor Q2 is in the OFF state, the On/Off pin is pulled high, which pulls the internal ENABLE# High and the module is OFF. To turn the module ON, Q2 is turned ON pulling the On/Off pin low resulting in the PWM ENABLE# pin going Low. The maximum voltage allowed on the On/Off pin is 7V. If Vin is used as a source, then a suitable external resistor R1 must be used to ensure that the voltage on the On/Off pin does not exceed 7V

Digital On/Off

Please see the Digital Feature Descriptions section.

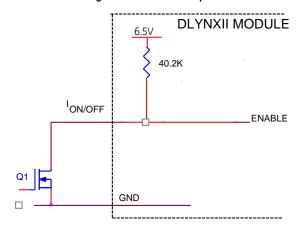


Figure 33. Circuit configuration for using positive On/Off logic.

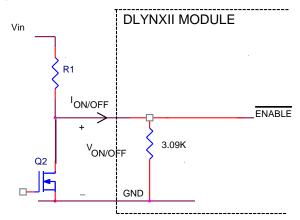


Figure 34. Circuit configuration for using negative On/Off logic.

Monotonic Start-up and Shutdown

The module has monotonic start-up and shutdown behavior for any combination of rated input voltage, output current and operating temperature range.

Startup into Pre-biased Output

The module can start into a prebiased output as long as the prebias voltage is 0.5V less than the set output voltage.

Analog Output Voltage Programming

The output voltage of the module is programmable to any voltage from 0.6dc to 3.63Vdc by connecting a resistor between the Trim and SIG_GND pins of the module. Certain restrictions apply on the output voltage set point depending on the input voltage. These are shown in the Output Voltage vs. Input Voltage Set Point Area plot in Fig. 35. The Upper Limit curve shows that for output voltages lower than 1V, the input voltage must be lower than the maximum of 14.4V. The Lower Limit curve shows that for output voltages

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

higher than 0.6V, the input voltage needs to be larger than the minimum of 4.5V. At output voltage of 2.5V, the input voltage should not be below 5Vin and at output voltage of 3.3V the input voltage should be at least 6Vin.

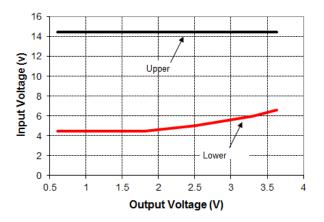
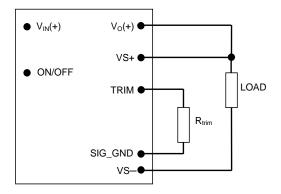


Figure 35. Output Voltage vs. Input Voltage Set Point Area plot showing limits where the output voltage can be set for different input voltages.



Caution – Do not connect SIG_GND to GND elsewhere in the layout

Figure 36. Circuit configuration for programming output voltage using an external resistor.

Without an external resistor between Trim and SIG_GND pins, the output of the module will be 0.6Vdc. To calculate the value of the trim resistor, *Rtrim* for a desired output voltage, should be as per the following equation:

$$Rtrim = \left[\frac{12}{(Vo - 0.6)} \right] k\Omega$$

Rtrim is the external resistor in $k\Omega$

Vo is the desired output voltage.

Table 1 provides Rtrim values required for some common output voltages.

Table 1

V _{O, set} (V)	Rtrim (KΩ)
0.6	Open
0.9	40
1.0	30
1.2	20
1.5	13.33
1.8	10
2.5	6.316
3.3	4.444

Digital Output Voltage Adjustment

Please see the Digital Feature Descriptions section.

Remote Sense

The power module has a Remote Sense feature to minimize the effects of distribution losses by regulating the voltage between the sense pins (VS+ and VS-). The voltage drop between the sense pins and the VOUT and GND pins of the module should not exceed 0.5V.

Analog Voltage Margining

Output voltage margining can be implemented in the module by connecting a resistor, R_{margin-up}, from the Trim pin to the ground pin for margining-up the output voltage and by connecting a resistor, R_{margin-down}, from the Trim pin to output pin for margining-down. Figure 37 shows the circuit configuration for output voltage margining. The POL Programming Tool or Power Module Wizard(PMW), available at www.gecriticalpower.com under the Downloads section, also calculates the values of R_{margin-up} and R_{margin-down} for a specific output voltage and % margin. Please consult your local GE technical representative for additional details.

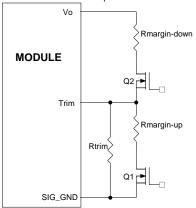


Figure 37. Circuit Configuration for margining Output voltage.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Digital Output Voltage Margining

Please see the Digital Feature Descriptions section.

Output Voltage Sequencing

The power module includes a sequencing feature, EZ-SEQUENCE that enables users to implement various types of output voltage sequencing in their applications. This is accomplished via an additional sequencing pin. When not using the sequencing feature, leave it unconnected.

When an analog voltage is applied to the SEQ pin, the output voltage tracks this voltage until the output reaches the set-point voltage. The final value of the SEQ voltage must be set higher than the set-point voltage of the module. The output voltage follows the voltage on the SEQ pin on a one-to-one basis. By connecting multiple modules together, multiple modules can track their output voltages to the voltage applied on the SEQ pin.

For proper voltage sequencing, first, input voltage is applied to the module. The On/Off pin of the module is left unconnected (or tied to GND for negative logic modules or tied to V_{IN} for positive logic modules) so that the module is ON by default. After applying input voltage to the module, a minimum 10msec delay is required before applying voltage on the SEQ pin. This delay gives the module enough time to complete its internal power-up soft-start cycle. During the delay time, the SEQ pin should be held close to ground (nominally $50\text{mV} \pm 20\text{ mV}$). This is required to keep the internal op-amp out of saturation thus preventing output overshoot during the start of the sequencing ramp. By selecting resistor R1 (see fig. 38) according to the following equation

$$R1 = \frac{26150}{6.5 - 0.05}$$
 = 4052 ohms, (4.02K Std.)

the voltage at the sequencing pin will be 50mV when the sequencing signal is at zero.

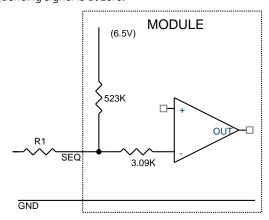


Figure 38. Circuit showing connection of the sequencing signal to the SEQ pin.

After the 10msec delay, an analog voltage is applied to the SEQ pin and the output voltage of the module will track this voltage on a one-to-one volt bases until the output reaches the set-point voltage. To initiate simultaneous shutdown of the modules, the SEQ pin voltage is lowered in a controlled manner. The output voltage of the modules tracks the voltages below their set-point voltages on a one-to-one basis. A valid input voltage must be maintained until the tracking and output voltages reach ground potential.

When using the EZ-SEQUENCE™ feature to control start-up of the module, pre-bias immunity during start-up is disabled. The pre-bias immunity feature of the module relies on the module being in the diode-mode during start-up. When using the EZ-SEQUENCE™ feature, modules goes through an internal set-up time of 10msec, and will be in synchronous rectification mode when the voltage at the SEO pin is applied. This will result in the module sinking current if a pre-bias voltage is present at the output of the module. When prebias immunity during start-up is required, the EZ-SEQUENCE™ feature must be disabled. For additional guidelines on using the EZ-SEQUENCE™ feature please refer to Application Note AN04-008 "Application Guidelines for Non-Isolated Converters: Guidelines for Sequencing of Multiple Modules", or contact the GE technical representative for additional information.

Overcurrent Protection

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current limiting continuously. At the point of current-limit inception, the unit enters hiccup mode. The unit operates normally once the output current is brought back into its specified range.

Digital Adjustable Overcurrent Warning

Please see the Digital Feature Descriptions section.

Overtemperature Protection

To provide protection in a fault condition, the unit is equipped with a thermal shutdown circuit. The unit will shut down if the over-temperature threshold of 122 (typ) is exceeded at the thermal reference point $T_{\rm ref}$. Please refer to Electrical characteristic table, over-temperature section on page 5. Once the unit goes into thermal shutdown it will then wait to cool before attempting to restart.

Digital Temperature Status via PMBus

Please see the Digital Feature Descriptions section.

Digitally Adjustable Output Over and Under Voltage Protection

Please see the Digital Feature Descriptions section.

Input Undervoltage Lockout

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will begin to operate at an input voltage above the undervoltage lockout turn-on threshold.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Digitally Adjustable Input Undervoltage Lockout

Please see the Digital Feature Descriptions section.

Digitally Adjustable Power Good Thresholds

Please see the Digital Feature Descriptions section.

Synchronization

The module switching frequency can be synchronized to a signal with an external frequency within a specified range. Synchronization can be done by using the external signal applied to the SYNC pin of the module as shown in Fig. 39, with the converter being synchronized by the rising edge of the external signal. The Module switches at half the SYNC frequency. The Electrical Specifications table specifies the requirements of the external SYNC signal. If the SYNC pin is not used, the module will free run at the default switching frequency. If synchronization is not being used, connect the SYNC pin to SIG_GND.

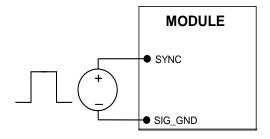


Figure 39. External source connections to synchronize switching frequency of the module.

Measuring Output Current, Output Voltage and Temperature

Please see the Digital Feature Descriptions section.

Dual Layout

Identical dimensions and pin layout of Analog and Digital MicroDLynxII modules permit migration from one to the other without needing to change the layout. In both cases the trim resistor is connected between trim and signal ground. The output of the analog module cannot be trimmed down to 0.51V

Tunable Loop™

The module has a feature that optimizes transient response of the module called Tunable LoopTM.

External capacitors are usually added to the output of the module for two reasons: to reduce output ripple and noise (see Figure 38) and to reduce output voltage deviations from the steady-state value in the presence of dynamic load current changes. Adding external capacitance however affects the voltage control loop of the module, typically causing the loop to slow down with sluggish response. Larger values of external capacitance could also cause the module to become unstable.

The Tunable $\mathsf{Loop}^\mathsf{TM}$ allows the user to externally adjust the voltage control loop to match the filter network connected to

the output of the module. The Tunable Loop™ is implemented by connecting a series R-C between the VS+ and TRIM pins of the module, as shown in Fig. 40. This R-C allows the user to externally adjust the voltage loop feedback compensation of the module.

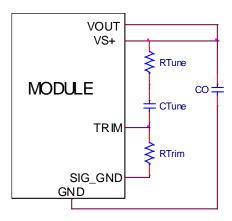


Figure. 40. Circuit diagram showing connection of R_{TUME} and C_{TUNE} to tune the control loop of the module.

Recommended values of R_{TUNE} and C_{TUNE} for different output capacitor combinations are given in Tables 2 and 3. Table 3 shows the recommended values of R_{TUNE} and C_{TUNE} for different values of ceramic output capacitors up to 1000uF that might be needed for an application to meet output ripple and noise requirements. Selecting R_{TUNE} and C_{TUNE} according to Table 3 will ensure stable operation of the module.

In applications with tight output voltage limits in the presence of dynamic current loading, additional output capacitance will be required. Table 3 lists recommended values of R_{TUNE} and C_{TUNE} in order to meet 2% output voltage deviation limits for some common output voltages in the presence of a 10A to 35A step change (50% of full load), with an input voltage of 12V.

Please contact your GE technical representative to obtain more details of this feature as well as for guidelines on how to select the right value of external R-C to tune the module for best transient performance and stable operation for other output capacitance values.

Table 2. General recommended values of of R_{TUNE} and C_{TUNE} for Vin=12V and various external ceramic capacitor combinations.

Со	16x47μF	20x47μF	24x47μF	30x47μF	40x47μF
R _{TUNE}	300	300	300	300	300
C _{TUNE}	470pF	560pF	680pF	820pF	1.2nF

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Table 3. Recommended values of R_{TUNE} and C_{TUNE} to obtain transient deviation of 2% of Vout for a 10A step load with Vin=12V.

Vo	3.3V	2.5V	1.8V	1.2V	0.6V
Co	8x47uF + 2x330uF	8x47uF + 4x330uF	8x47uF + 7x330uF	8x47uF + 14x330uF	8x47uF + 24x330uF
RTUNE	221Ω	221Ω	221Ω	300Ω	300Ω
C _{TUNE}	2700pF	3300pF	4700pF	10nF	18nF
ΔV	50mV	43mV	32mV	18mV	12mV

Note: The capacitors used in the Tunable Loop tables are 47 µF/3 m Ω ESR ceramic and 330 µF/12 m Ω ESR polymer capacitors.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Digital Feature Descriptions

PMBus Interface Capability

The 35A Digital MicroDLynxII™ power modules have a PMBus interface that supports both communication and control. The PMBus Power Management Protocol Specification can be obtained from www.pmbus.org. The modules support a subset of version 1.1 of the specification (see Table 6 for a list of the specific commands supported). Most module parameters can be programmed using PMBus and stored as defaults for later use.

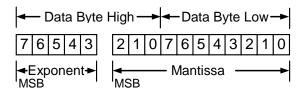
All communication over the module PMBus interface must support the Packet Error Checking (PEC) scheme. The PMBus master must generate the correct PEC byte for all transactions, and check the PEC byte returned by the module.

The module also supports the SMBALERT# response protocol whereby the module can alert the bus master if it wants to talk. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The module has non-volatile memory that is used to store configuration settings. Not all settings programmed into the device are automatically saved into this non-volatile memory, only those specifically identified as capable of being stored can be saved (see Table 6 for which command parameters can be saved to non-volatile storage).

PMBus Data Format

For commands that set thresholds, voltages or report such quantities, the module supports the "Linear" data format among the three data formats supported by PMBus. The Linear Data Format is a two byte value with an 11-bit, two's complement mantissa and a 5-bit, two's complement exponent. The format of the two data bytes is shown below:



The value is of the number is then given by $Value = Mantissa \times 2^{Exponent}$

PMBus Addressing

The power module can be addressed through the PMBus using a device address. The module has 64 possible addresses (0 to 63 in decimal) which can be set using resistors connected from the ADDR0 and ADDR1 pins to GND. Note that some of these addresses (0, 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 12, 40, 44, 45, 55 in decimal) are reserved according to the SMBus specifications and may not be useable. The address is set in the form of two octal (0 to 7) digits, with each pin setting one digit. The ADDR1 pin sets the high order digit and ADDR0 sets the low order digit. The resistor values suggested for each digit are shown in Table 4 (1% tolerance resistors are recommended). Note that if

either address resistor value is outside the range specified in Table 4, the module will respond to address 127.

Table 4

Digit	Resistor Value (KΩ)
0	11
1	18.7
2	27.4
3	38.3
4	53.6
5	82.5
6	127
7	187

The user must know which I²C addresses are reserved in a system for special functions and set the address of the module to avoid interfering with other system operations. Both 100kHz and 400kHz bus speeds are supported by the module. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, smbus.org.

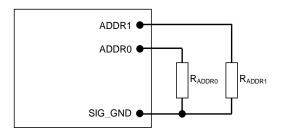


Figure 41. Circuit showing connection of resistors used to set the PMBus address of the module.

Operation (01h)

This is a paged register. The OPERATION command can be use to turn the module on or off in conjunction with the ON/OFF pin input. It is also used to margin up or margin down the output voltage

PMBus Enabled On/Off

The module can also be turned on and off via the PMBus interface. The OPERATION command is used to actually turn the module on and off via the PMBus, while the ON_OFF_CONFIG command configures the combination of analog ON/OFF pin input and PMBus commands needed to turn the module on and off. Bit [7] in the OPERATION command data byte enables the module, with the following functions:

0 : Output is disabled1 : Output is enabled

This module uses the lower five bits of the ON_OFF_CONFIG data byte to set various ON/OFF options as follows:

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Bit Position	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r
Function	PU	CMD	CPR	POL	CPA
Default Value	1	0	1	1	0

PU: Sets the default to either operate any time input power is present or for the ON/OFF to be controlled by the analog ON/OFF input and the PMBus OPERATION command. This bit is used together with the CP, CMD and ON bits to determine startup.

Bit Value	Action
0	Module powers up any time power is present regardless of state of the analog ON/OFF pin
1	Module does not power up until commanded by the analog ON/OFF pin and the OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

CMD: The CMD bit controls how the device responds to the $\ensuremath{\mathsf{OPERATION}}$ command.

Bit Value	Action
0	Module ignores the ON bit in the
	OPERATION command
1	Module responds to the ON bit in the
1	OPERATION command

CPR: Sets the response of the analog ON/OFF pin. This bit is used together with the CMD, PU and ON bits to determine startup.

Bit Value	Action
0	Module ignores the analog ON/OFF pin, i.e. ON/OFF is only controlled through the PMBUS via the OPERATION command
1	Module requires the analog ON/OFF pin to be asserted to start the unit

CPA: Sets the action of the analog ON/OFF pin when turning the controller OFF. This bit is internally read and cannot be modified by the user

PMBus Adjustable Soft Start Rise Time

The soft start rise time can be adjusted in the module via PMBus. When setting this parameter, make sure that the charging current for output capacitors can be delivered by the module in addition to any load current to avoid nuisance tripping of the overcurrent protection circuitry during startup. The TON_RISE command sets the rise time in ms, and allows choosing soft start times between 600µs and 9ms, with possible values listed in Table 5. Note that the exponent is fixed at -4 (decimal) and the upper two bits of the mantissa are also fixed at 0.

Table 5

Rise Time	Exponent	Mantissa
600µs	11100	0000001010
900µs	11100	0000001110
1.2ms	11100	0000010011
1.8ms	11100	00000011101
2.7ms	11100	00000101011
4.2ms	11100	00001000011
6.0ms	11100	00001100000
9.0ms	11100	00010010000

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Output Voltage Adjustment Using the PMBus

The VREF_TRIM parameter is important for a number of PMBus commands related to output voltage trimming, and margining. Each of the 2 output voltages of the module can be set as the combination of the voltage divider formed by RTrim and a 20k Ω upper divider resistor inside the module, and the internal reference voltage of the module. The reference voltage VREF is be nominally set at 600mV, and the output regulation voltage is then given by:

$$V_{OUT} = \left\lceil \frac{20000 + RTrim}{RTrim} \right\rceil \times V_{REF}$$

Hence the module output voltage is dependent on the value of RTrim which is connected external to the module.

The VREF TRIM parameter is used to apply a fixed offset voltage to the reference voltage can be specified using the "Linear" format and two bytes. The exponent is fixed at -9(decimal). The resolution of the adjustment is 7 bits, with a resulting step size of approximately 0.4%. The maximum trim range is -20% to +10% of the nominal reference voltage(600mV) in 2mV steps. Possible values range from -120mV to +60mV. The exception is at 0.6Vout where the allowable trim range is only -90mV to +60mV to prevent the module from operating at lower than 0.51Vdc. When trimming the voltage below 0.6V, the module max. input voltage operating point also reduces proportionally. As shown earlier in Fig.41, the maximum permissible input voltage is 13V. For any voltage trimmed below 0.6V, the maximum input voltage will have to be reduced by the same factor.

When PMBus commands are used to trim or margin the output voltage, the value of V_{REF} is what is changed inside the module, which in turn changes the regulated output voltage of the module.

The nominal output voltage of the module is adjustable with a minimum step size of 0.4% over a +10% to -20% range from nominal using the VREF_TRIM command over the $\frac{\text{PMR}_{12}}{\text{CM}_{22}}$

The VREF_TRIM command can be used to apply a fixed offset voltage to either of the output voltage command value using the "Linear" mode with the exponent fixed at -9 (decimal). The value of the offset voltage is given by

$$V_{REF\ (offset)} = VREF\ _TRIM \times 2^{-9}$$

This offset voltage is added to the voltage set through the divider ratio and nominal V_{REF} to produce the trimmed output voltage. If a value outside of the +10%/-20% adjustment range is given with this command, the module will set it's output voltage to the upper or lower limit value (as if VOUT_TRIM, assert SMBALRT#, set the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

Applications Example

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 20mV.

- The internal reference voltage is 0.6V. So we need to determine how the 20mV translates to a change in the internal reference voltage.
- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 20mV change at 1.8Vo requires a 0.33x20mV = 6.6mV change in the reference voltage.
- Vref(offset) = (6.6)/1000 = 0.0066 Volts (- sign since we are trimming down)
- V_{ref(offset)} = V_{ref_Trim} x 2 -9
- V_{ref_Trim} = V_{ref(offset)} x 512
- $V_{ref_Trim} = -0.0066 \times 512 = -3.3 = -3$ (rounded to nearest integer

Output Voltage Margining Using the PMBus

The module can also have its output margined via PMBus commands. The command STEP_VREF_MARGIN_HIGH will set the margin high voltage, while the command STEP_VREF_MARGIN_LOW sets the margin low voltage. Both the STEP_VREF_MARGIN_LOW commands will use the "Linear" mode with the exponent fixed at -9 (decimal). Two bytes are used for the mantissa with the upper bit [7] of the high byte fixed at 0. The actual margined output voltage is a combination of the STEP_VREF_MARGIN_HIGH or STEP_VREF_MARGIN_LOW and the VREF_TRIM values as shown below. The net permissible voltage range change is -30% to +10% for the margin high command and -20% to 0% for the margin low command

 $V_{REF\,(MH)} =$

 $(STEP_VREF_MARGIN_HIGH+VREF_TRIM) \times 2^{-9}$

Applications Example

For a design where the output voltage is 1.2V and the output needs to be trimmed up by 100mV (within 10% of Vo).

- The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.
- Divider Ratio = Vref/Vout = 0.6/1.2 = 0.5
- Hence a 100mV change at 1.2Vo requires a 0.5x100mV = 50mV change in the reference voltage.
- $V_{REF(MH)} = (50)/1000 = 0.05 \text{ Volts}$
- VREF(MH) = (Step_Vref_margin_high + Vref_trim) x 2 -9
- Assume V_{ref_Trim} = 0 here
- Step_V_{ref_margin_high} = V_{REF(MH)} x 512
- Step_V_{ref_margin_high} = 0.05 × 25.6 = 26 (rounded to nearest integer

 $V_{REF\,(ML)} =$

 $(STEP_VREF_MARGIN_LOW + VREF_TRIM) \times 2^{-9}$

Applications Example

For a design where the output voltage is 1.8V and the output needs to be trimmed down by 100mV (within -20% of Vo).

- The internal reference voltage is 0.6V. So we need to determine how the 100mV translates to a change in the internal reference voltage.
- Divider Ratio = Vref/Vout = 0.6/1.8 = 0.33
- Hence a 100mV change at 1.2Vo requires a 0.33x100mV = 33mV change in the reference voltage.
- $V_{REF(MH)} = -(33)/1000 = -0.033$ Volts (- sign since we are margining down)

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

- VREF(ML) = (Step_Vref_margin_low + Vref_trim) x 2 -9
- Assume V_{ref_Trim} = 3 here (from V_{Ref_Trim} example earlier)
- Step_Vref_margin_low = VREF(ML) x 512 Vref_trim
- Step_V_{ref_margin_low} = $-0.033 \times 512 (-3) = -16.9 + 3 = -13.9 = -14$ (rounded to nearest integer

The module will support the margined high or low voltages using the OPERATION command. Bits [5:2] are used to enable margining as follows:

• 00XX : Margin Off

0101 : Margin Low (Act on Fault)
0110 : Margin Low (Act on Fault)
1001 : Margin High (Act on Fault)
1010 : Margin High (Act on Fault)

PMBus Adjustable Overcurrent Warning

The module can provide an overcurrent warning via the PMBus. The threshold for the overcurrent warning can be set using the parameter IOUT_OC_WARN_LIMIT. This command uses the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte represent the mantissa. The exponent is fixed at –1 (decimal). The upper five bits of the mantissa are fixed at 0 while the lower six bits are programmable with a default value of 19A (decimal). The resolution of this warning limit is 500mA. The value of the IOUT_OC_WARN_LIMIT can be stored to nonvolatile memory using the STORE_DEFAULT_ALL command

Temperature Status via PMBus

The module will provide information related to temperature of the module through the READ_TEMPERATURE_2 command. The command returns external temperature in degrees Celsius. This command will use the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte will represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte will represent the mantissa. The exponent is fixed at 0 (decimal). The lower 11 bits are the result of the ADC conversion of the external temperature

PMBus Adjustable Output Over, Under Voltage Protection and Power Good

The module has a common command to set the PGOOD, VOUT_UNDER_VOLTAGE(UV) and VOUT_OVER_VOLTAGE (OV) limits as a percentage of nominal. Refer to Table 6 of the next section for the available settings. The PMBus command VOUT_OVER_VOLTAGE (OV) is used to set the output over voltage threshold from two possible values: +12.5% or +16.67% of the commanded output voltage for each output.

The module provides a Power Good (PGOOD) that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal is de-asserted to a low state if any condition such as overtemperature, overcurrent or loss

of regulation occurs that would result in the output voltage going outside the specified thresholds. The PGOOD thresholds are user selectable via the PMBus (the default values are as shown in the Feature Specifications Section). Each threshold is set up symmetrically above and below the nominal value. The PGL (POWERGOODLOW) command will set the output voltage level above which PGOOD is asserted (lower threshold). The PGH(POWERGOODHIGH) command will set the level above which the PGOOD command is deasserted. This command will also set two thresholds symmetrically placed around the nominal output voltage. Normally, the PGL threshold is set higher than the PGH threshold.

The PGOOD terminal can be connected through a pullup resistor (suggested value $100 \mathrm{K}\Omega$) to a source of 5VDC or lower. The current through the PGood terminal should be limited to a max value of 5mA

PMBus Adjustable Input Undervoltage Lockout

The module allows for adjustment of the input under voltage lockout and hysteresis. The command VIN_ON allows setting the input voltage turn on threshold for each output, while the VIN_OFF command will set the input voltage turn off threshold. For the VIN_ON command, possible values are 4.25V to 16V in variable steps. For the VIN_OFF command, possible values are 4V to 15.75V in 0.5V steps. If other values are entered for either command, they is mapped to the closest of the allowed values.

Both the VIN_ON and VIN_OFF commands use the "Linear" format with two data bytes. The upper five bits will represent the exponent (fixed at -2) and the remaining 11 bits will represent the mantissa. For the mantissa, the four most significant bits are fixed at 0.

Measurement of Output Current and Voltage

The module is capable of measuring key module parameters such as output current and voltage and providing this information through the PMBus interface.

Measuring Output Current Using the PMBus

The module measures current by using the inductor winding resistance as a current sense element. The inductor winding resistance is then the current gain factor used to scale the measured voltage into a current reading. This gain factor is the argument of the IOUT_CAL_GAIN command, and consists of two bytes in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –15 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa. During manufacture, each module is calibrated by measuring and storing the current gain factor into non-volatile storage.

The current measurement accuracy is also improved by each module being calibrated during manufacture with the offset in the current reading. The IOUT_CAL_OFFSET command is used to store and read the current offset. The argument for this command consists of two bytes composed of a 5-bit exponent (fixed at -4d) and a 11-bit

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

mantissa. This command has a resolution of 62.5mA and a range of $\,$ -4000mA to +3937.5mA.

The READ_IOUT command provides module average output current information. This command only supports positive or current sourced from the module. If the converter is sinking current a reading of 0 is provided. The READ_IOUT command returns two bytes of data in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa with the 11th bit fixed at 0 since only positive numbers are considered valid.

Measuring Output Voltage Using the PMBus

The module provides output voltage information using the READ_VOUT command for each output. In this module the output voltage is sensed at the remote sense amplifier output pin so voltage drop to the load is not accounted for. The command will return two bytes of data all representing the mantissa while the exponent is fixed at -9 (decimal).

Reading the Status of the Module using the PMBus

The module supports a number of status information commands implemented in PMBus. However, not all features are supported in these commands. A 1 in the bit position indicates the fault that is flagged.

STATUS_BYTE: Returns one byte of information with a summary of the most critical device faults.

Bit Position	Flag	Default Value
7	X	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

STATUS_WORD: Returns two bytes of information with a summary of the module's fault/warning conditions.

Bit Position	Flag	Default Value
7	X	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

High Byte

Bit Position	Flag	Default Value
7	VOUT fault or warning	0

6	IOUT fault or warning	0
5	X	0
4	MFR	0
3	POWER_GOOD# (is negated)	0
2	X	0
1	X	0
0	X	0

STATUS_VOUT: Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	VOUT OV Fault	0
6	X	0
5	X	0
4	VOUT UV Fault	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_IOUT: Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	IOUT OC Fault	0
6	X	0
5	IOUT OC Warning	0
4	X	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_TEMPERATURE: Returns one byte of information relating to the status of the module's temperature related faults.

Bit Position	Flag	Default Value
7	OT Fault	0
6	OT Warning	0
5	X	0
4	X	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_CML: Returns one byte of information relating to the status of the module's communication related faults.

Bit Position	Flag	Default Value
7	Invalid/Unsupported Command	0
6	Invalid/Unsupported Command	0
5	Packet Error Check Failed	0
4	Memory Fault Detected	0

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

3	X	0
2	X	0
1	Other Communication Fault	0
0	X	0

MFR_VIN_MIN: Returns minimum input voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -2, and lower 11 bits are mantissa in two's complement format – fixed at 12)

MFR_VOUT_MIN: Returns minimum output voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -10, and lower 11 bits are mantissa in two's complement format – fixed at 614)

MFR_SPECIFIC_00: Returns information related to the type of module and revision number. Bits [7:2] in the Low Byte indicate the module type (010011 corresponds to the UJT035 series of module), while bits [7:3] indicate the revision number of the module.

Low Byte

Bit Position	Flag	Default Value
7:2	Module Name	010011
1:0	Reserved	10

High Byte

Bit Position	Flag	Default Value
7:3	Module Revision Number	None
2:0	Reserved	000

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Summary of Supported PMBus Commands

Please refer to the PMBus 1.1 specification for more details of these commands.

Table 6

Hex Code	Command		Brief Description										
		Turn Module on or o	off. Also	used to	margii	n the ou	itput vol	tage			Memory Storage		
		Format				Unsigne	ed Binar	/					
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r/w	r	r/w	r/w	r/w	r/w	r	r			
		Function	On	Х		Ma	rgin		Х	X			
		Default Value	0	0	0	0	0	0	Х	Χ			
01	OPERATION	Bit 7: 0 Output swit	ching d	isabled									
		1 Output s	witchin	g enabl	ed								
		Margin: 00XX Margin Off											
		0101 Marg											
		0110 Marg											
		1001 Marg											
		1010 Marg Configures the ON/					:		011/05	F =:=			
		and PMBus commo		ictionali	ty us u	COMBIN	ation of	analog	ON/OF	r þin			
		Format	irius			Unciana	ed Binar	,					
		Bit Position	7	6	5	4	3	2	1	0			
02	ON_OFF_CONFIG	Access	r	r	r	r/w	r/w	r/w	r/w	r	YES		
		Function	X	X	X	pu	cmd	cpr	pol	сра			
		Default Value	0	0	0	1	0	1	1	0			
			_	_	_	_				Ŭ			
			ofer to Page 19 for details on pu, cmd, cpr, pol and cpa ear any fault bits that may have been set, also releases the SMBALERT# signal										
03	CLEAR_FAULTS		the device has been asserting it.										
			Used to control writing to the module via PMBus. Copies the current register										
			etting in the module whose command code matches the value in the data byte nto non-volatile memory (EEPROM) on the module										
		Format	emory (EEPROM			ed Binar	,					
		Bit Position	7	6	5	orisigne 4	3	2	1	0			
		Access	r/w	r/w	r/w	X	X	X	X	×			
		Function	bit7	bit6	bit5	X	X	X	X	X			
		Default Value	0	0	0	X	X	X	X	X			
10	WRITE_PROTECT	Bit5: 0 – Enables all	writes		itted in		bit7				YES		
		1 – Disables all						AGE OP	ERATIO	N			
		and ON_OF											
		Bit 6: 0 – Enables al											
		1 – Disables al						T, PAGE	and				
		OPERATION											
		Bit7: 0 – Enables all 1 – Disables all	writes	us perri	for the l	MILS OF	DILO DRATEAT	Comm	and				
		(bit5 and bit			or the v	/VINIT_F	NOTEC	COITIII	iuiiu				
-		(Sits did bli		20 01									
		Ctoros all of the	ront -1	rable	naicts -	ottin -	in the F		men	aa +L -			
15	STORE_USER_ALL	Stores all of the cur new defaults on po		nable re	egisters	settings	in the E	EPROM	memor	y us trie			
		new delduits on po	wei up										
-													
		Restores all of the s											
16	RESTORE_USER_ALL	(EEPROM). The command should not be used while the device is actively											
		switching											
-		This command helps the host system/GUI/CLI determine key capabilities of the											
		module	os u IE N	usi sysl	c111/UUI	, cli uei	.emme	ney cup	Jubilitie	5 UI II IE			
		Format				Unsigne	ed Binar	/					
		Bit Position	7	6	5	4	3	2	1	0			
		Access	r	r	r	r	r	r	r	r			
19	CAPABILITY	Function	PEC		D .	ALRT	'		rved				
		Default Value	1	0	1	1	0	0	0	0			
		PEC – 1 Supported				•							
		SPD -01 - max of 4	00kHZ										
		ALRT – 1 – SMBALERT# supported											

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Hex Code	Command		Brief Description									
		The module has MC		to Line	ar and E	xponen	t set to	-10. Th	ese valı	ues	Memory Storage	
		cannot be changed Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
20	VOUT_MODE	Function	'	Mode		'		Expone		<u> </u>		
		Default Value	0	0	0	1	0	1	1	1		
		Mode: Value fixed o										
		Exponent: Value fix	ed at 10	0111, Ex	kponent	for line	ar mod	e value	s is -9			
		Sets the value of in	put volt		which th Linear, tu				in.			
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
		Function			Exponer	nt	•		Mantiss	sa		
		Default Value	1	1	1	1	0	0	0	0		
		Bit Position	7	6	5	4	3	2	1	0		
		Access Function	r	r/w	r/w	r/w	r/w tissa	r/w	r/w	r/w		
		Default Value	0	0	0	1	0	0	0	1		
35	VIN_ON	Exponent -2 (dec), f	-	U	0		U	U	U		YES	
		Mantissa										
		The upper four bits										
		The lower seven are	e progr	ammab	le with	a defaul	t value	of 9(de	c). This			
		corresponds to a de					es are					
		• 4.25, in s										
		• 13V to 1										
		20, 10 2										
		Sets the value of input voltage at which the module turns off										
			put volt									
		Format	_	1	inear, tu					0		
		Bit Position Access	7 r	6 r	5 r	4 r	3 r	2 r	1 r	0 r		
		Function	ı		<u> </u>		ı		Mantiss			
		Default Value	1	1	1	1	0	0	0	0		
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w		
		Function		1			tissa	1				
		Default Value	0	0	0	1	0	0	0	0	ı	
36	VIN_OFF	Exponent -2 (dec), f Mantissa	ixea								YES	
	·e	The upper four bits	are fixe	od at 0							120	
		The lower seven are			le with o	a defaul	t value	of 8(de	c). This			
		corresponds to a de	efault o									
		Allowable values ar			0 7							
		4.00, in s10.25V t					,					
		• 10.25V t	.0 11./5	ov ittitli	Lienient	S UI U.5'	V					
		• 13.75V t	o 16 75	SV in inc	rement	of 1V						
		13.75			2							
			C - 1				1					
		Returns the value o	the go	ain corr	ection te	erm use	d to co	rect th	e meası	ured		
		output current Format			_inear, t\	NO'S CO	nnleme	nt hine	ırv			
		Bit Position	7	6	5 5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r/w		
38	IOUT_CAL_GAIN	Function			Exponer	nt			Mantiss		YES	
		Default Value	1	0	0	0	1	0	0	V		
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w		
		Function Mantissa Default Value V: Variable based on factory calibration										
		Detault value		V: V	uriable b	oused or	1 tactor	y calibi	ution		ı	

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Hex Code	Command			Br	ief Desc	ription					Non-Volatile Memory Storage	
		Returns the value o	of the of	fset cor	rection	used to	correct	the me	easured	output		
		current Format			inear, tu	vo's cor	mnleme	nt hina	rv			
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r/w	r	r		
39	IOUT_CAL_OFFSET	Function			Exponer				Mantiss		YES	
		Default Value Bit Position	7	1	1	0	3	V	V	V		
		Access	r	6 r	5 r/w	r/w	r/w	2 r/w	1 r/w	0 r/w		
		Function	'		17 00		tissa	17 00	17 00	1700		
		Default Value		V: Vo	ariable b	ased o	n factor	y calibr	ation			
		Sets the output ove	ercurren	nt fault l	evel in A	(canno	t be ch	anged)		<u> </u>		
		Format			Linear, tv				ry			
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
46	IOUT_OC_FAULT_LIMIT	Function Default Value	1	1	Exponer 1	1	1	0	Mantiss 0	0	YES	
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w		
		Function			1	Man	tissa		1			
	Value maybe locked	Default Value	0	1	0	1	1	0	1	0		
	·		Determines module action in response to an IOU_OC_FAULT_LIMIT or a VOUT									
		undervoltage (UV) f										
		Format			l	Jnsigne	d Binar	у				
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r/w	r/w	r/w	r	r	r		
, ,	IOLIT OC FALLET DECDONICE	Function	Х	Χ	RS [2]	RS [1]	RS [0]	×	Х	X	VEC	
47	47 IOUT_OC_FAULT_RESPONSE	Default Value	0	0	1	1	1	1	0	0	YES	
		RS[2:0] – Retry Setti 000 Unit do 111 Unit go Any other v	oes not oes thro	ugh no	rmal sot	t start o	continu	ously				
4A	IOUT_OC_WARN_LIMIT	Sets the output over IOUT_OC_FAULT_LIFORMAT Bit Position Access Function Default Value Bit Position Access Function Default Value Bit Position Access Function Default Value		6 r	ng level inear, tv 5 r Exponer 1 5 r/w	4 r t 1 4 r/w		ent bina 2 r		0 r		
4F	OT_FAULT_LIMIT	Sets the overtemper Format Bit Position Access Function Default Value Bit Position Access Function Default Value	7 r 0 7 r/w 0 0	6 r	vel in °C inear, tv 5 r Exponer 0 5 r/w	4 r t 0 4 r/w	mpleme 3 r 0 3 r/w tissa 1	2 r	ry 1 r Mantiss 0 1 r/w	0 r GG 0 0 r/w	YES	
	Value may be locked	Delault value							<u> </u>	J		

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Table 6 (Continued)

Hex Code	Command				Brief	Descript	tion					Non-Volatile Memory Storage
- couc		Sets the over temper	erature	e warnin	g level i	n °C. Mı	ust be lo	wer tho	ın OT F	AULT I	LIMIT	- Temory Storage
		Format				wo's cor						
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	٢		
51		Function			Exponer	nt		١	1antiss	נ		YES
31	OT_WARN_LIMIT	Default Value	0	0	0	0	0	0	0	0		11.5
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	4	
		Function Default Value	0	1	1		tissa 1	0	0	1	-	
		L	-		1	-		U	U	1		
		Sets the rise time of	f the o	utput vo	ltage du	ıring sta	ırtup.					
		Supported Values –							of 0 insti	ucts u	nit to	
		bring its output to p	rograi			wo's cor			\ /			
		Bit Position	7	6	5	4	3	2	y 1	0		
		Access	r	r	r	r	r	r	r	r/w	†	
61	TON_RISE	Function	'		Exponer				1antiss			YES
		Default Value	1	1	1	0	0	0	0	0	1	
		Bit Position	7	6	5	4	3	2	1	0	1	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w]	
		Function				Man						
		Default Value	0	1	0	0	0	0	1	1		
		Returns one byte of	inforn	nation w					ical mo	dule fa	<u>u</u> lts	
		Format		_		Unsigne						
		Bit Position	7	6	5	4	3	2	1	0		
78	STATUS_BYTE	Access	r	r	r	r	r	r	r	r		
	· · · · -	Floor	V	OFF	VOUT	IOUT_	VIN_U	TEMP	CMI	None of the		
		Flag	Х	OFF	_OV	OC	V	TEMP	CML	Above		
		Default Value	0	0	0	0	0	0	0	0		
		Returns two bytes of	of infor	mation	with a s	ummary	of the	module'	s fault/v	warnin	g g	
		conditions										
		Format					Unsign	ned Bind	ary			
		Bit Position		7	6	5	4	3		2	1	
		Access		r	r	r	r	r		r	r	
		Flag	V	OUT I	OUT/P	Χ	MFR	PGO	OD	X	Χ	
79	STATUS_WORD				OUT							
, ,	31/1103_0010	Default Value		0	0	0	0	0		0	0	
		Bit Position		7	6	5	4	3		2	1	4
		Access		r	r	r	r	r		r	r	4
		el		, l		VOUT_ OV	IOUT	0 ,,,,			CMI NO]
		Flag		X C)FF	ov _	C	VIN_	UVIIE	MP	CML	
		Default Value		0	Х	0	0	0	-	0	0	<u> </u>
-				-						-		
		Returns one byte of	inforn	nation w	ith the	status of	t the mo	odule's c	output v	oltage	related	
		faults				Unciana	d Dipo-	,				
7A	CTATUS VIOLIT	Format Bit Position		7	6 5	Unsigne	a Binary 4		2 1	0		
/ A	STATUS_VOUT	Access		r	r 1	_	r		r r	r	†	
		Flag		IT_OV	X		JT_UV		X X	X	†	
		Default Value		0)	0		0 0	0	1	
<u> </u>						•			•	•		
		Returns one byte of	inforn	nation w	ith the	status of	f the mo	odule's c	output c	urrent	related	
		faults Format Unsigned Binary										
70	7B STATUS_IOUT	Format Bit Desition		7	6	Unsi		nary	4 3	1 2 1	1 0	
l 'B		Bit Position Access		7 r	6 r		5 r		4 3 r r	_	1 0 r r	
		Flag	IOI IT	 OC Fat		IOI IT	OC War	rnina	XX		XX	
		Default Value	1001	0	0	1001	00 000	illig	0 0		0 0	
		Delault Value				<u> </u>	J		0 0	U	J U	

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Hex Code	Command		Brief Description											Non-Volatile Memory Storage
		Returns one byte of	of infor	matic	n with	n the st	atus of	the r	modul	e's te	mperat	ture re	lated	
		Format				116	nsigned	Ring	arv					
7D	STATUS_TEMPERATURE	Bit Position		7		6	5			3	2 1	0		
10	3771103_12111	Access		r		r	r	_		_	r r	r		
		Flag	OT_	FAUL	.T (T_WAF	RN X		X Z	X :	ХХ	Х		
		Default Value		0		0	0		0 (0	0 0	0		
		Returns one byte of information with the status of the module's communication related faults												
		Format					Unsigne	ed Bi	nary					
		Bit Position	7		6	5	4		3	2	1		0	
7E	STATUS_CML	Access	r		r	r	r		r	r	r		r	
		Flag	Invo Comn		Inval Data		Memo faul detec	ť	X	Χ	Oth Com Fau	nm	X	
		Default Value	0		0	0	0		0	0	0		0	
		Returns one byte	of infor	matic	n with	n the st	atus of	the r	modul	e spe	cific fa	ults or	warning	
		Format				Unsig	gned Bir	nary					•	
		Bit Position	7	6	5	4	3	2	1		0			
		Access	r	r	r	r	r	r	r		R			
80	STATUS_MFR_SPECIFIC	Flag	OTFI	×	Х	IVADD	R X	Х	Х	TW	OPH_EN	٨		
		Default Value	0	0	0	0	0	0	0		0			
		OTFI – Internal Temperature above Thermal Shutdown threshold IVADDR – PMBUs address is not valid TWOPH_EN – Module is in 2 phase mode												
		Returns the value	of the	outpu	ıt volta	age of t	he mod	lule.	Ехро	nent i	s fixed	at -9.		
		Format					o's com							
		Bit Position	7	_	6	5	4	3	_	2	1	0	_	
		Access Function	r		r	r	r Manti	r		r	r	r		
8B	READ_VOUT	Default Value	0		0	0	Manti 0	0		o T	0	0	1	
		Bit Position	7		6	5	4	3		2	1	0	1	
		Access	r		r	r	r	r		r	r	r]	
		Function				0 1	Manti						4	
		Default Value	0		0	0	0	0		0	0	0	J	
		Returns the value	of the	outpu									_	
		Format					o's com							
		Bit Position	7		6	5	4	3	_	2	1	0	4	
		Access Function	r		r Fx	r ponent	r	R	-	r M	r antissa	r	1	
8C	READ_IOUT	Default Value	1		1	1	0	0	١	V	V	V	1	
	_	Bit Position	7		6	5	4	3		2	1	0]	
		Access	r		r	r	r	r		r	r	r	1	
		Function Default Value	V	-	V	V	Manti V	ssa V	1	<i>y</i> T	V	0	1	
		Default Value V - Variable	V		v	V	V	V	'	v	V	U	J	
		V - Variable												

GE

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules 4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Table 6 (Continued)

Hex Code	C											Non-Volatile
	Command				Brief D	escripti	ion					Memory Storage
		Returns the value o	f the ex	ternal t	empera	ture in o	dearee (Celsius				
		Format				vo's cor			ſy			
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	R	r	r	r		
		Function		E	xponer	nt		1	Mantiss	a		
8E	READ_TEMPERATURE_2	Default Value	0	0	0	0	0	V	V	V		
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
		Function				Man	tissa					
		Default Value	V	V	V	V	V	V	V	0		
		V - Variable										
		Raturns one hyte in	dicating	the m	ai ماريام	compli	ant to P	MRuc Si	nec 11	Iread or	alv)	
		Returns one byte indicating the module is compliant to PMBus Spec. 1.1 (read only) Format Unsigned Binary										
98	PMBUS REVISION	Bit Position	7	6	5	4	3	2	1	0		
55	111005_1101014	Access	r	r	r	r	r	r	r	r		
		Default Value	0	0	0	1	0	0	0	1		
T		Returns module na	me info	rmation								
		Format				Jnsigne	d Binar	У				
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
D0	MFR SPECIFIC 00	Function		•		Rese			•			YES
	1 11 1 <u>-</u> 31 2011 10 <u>-</u> 00	Default Value	0	0	0	0	0	0	0	0		123
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r	r	r	r	r		
		Function		1 1		Name	1 1	1 1		erved		
		Default Value	0	1	0	0	1	1	0	0		
		Applies a fixed offse										
		steps. Permissible v					and +6	0mV. Ir	ne offset	t is calcu	ılated	
		as VREF_TRIMx2-9. E	xponer				malama	nt bina	c) /			
		Bit Position	7	6	iriear, to	vo's cor 4	3	2	у 1	0		
		Access	r/w	r	r	r	r	r	r	r		
D4	VREF_TRIM	Function	17 VV			Man		'		_ '		YES
		Default Value	V	V	V	V	V	V	V	V		
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w		
		Function		· · · · ·			tissa					
		Default Value	V	V	V	V	V	V	V	V		
		Applies a fixed offse	at to the	refere	nce valt	nne Adi	iustmer	nt is N%	t∩ ±1∩0	6 in 2m1	/ stens	
		Permissible values i									sicps.	
		(STEP_VREF_MARGI									out	
		voltage includes VR	EF TRI	4 adius	tment a	nd rana	es from	1 -30% t	to 10%			
		Format				vo's cor						
		Bit Position	7	6	5	4	3	2	1	0		
D5	D5 STEP_VREF_MARGIN_HIGH	Access	r	r	r	r	r	r	r	r		YES
		Function				Man	tissa					
		Default Value	V	V	V	V	V	V	V	V		
		Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r	r/w	r/w	r/w	r/w	r/w		
		Function					tissa	1				
		Default Value	V	V	V	V	V	V	V	V		

35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc –14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Table 6 (Continued)

Hex Code	Command					Bri	ef De	escript	ion					Non-Volatile Memory Storage
		Applies a fixed n steps. Permissib (STEP_VREF_MAI voltage includes	le value RGIN_L	es ran OW +	ge be VREF	etwee	n -12 1)x2-	20mV (9.Expo	and 0m nent fix	V) The e ed at -9	offset is (dec). N	calculate	ed as	
		Format				Line	ır, tw	o's co	mpleme	ent bind	ıry			
		Bit Position		7	6	Ü	5	4	3	2	1	0		
D6	STEP_VREF_MARGIN_LOW	Access		r	r	1		r	r	r	r	r		YES
		Function						Mar	ntissa	•				
		Default Value	e	V	V	/	/	V	V	V	V	V		
		Bit Position		7	6		5	4	3	2	1	0		
		Access		r	r	r/	w	r/w	r/w	r/w	r/w	r/w		
		Function		-				Mar	ntissa	•			1	
		Default Value	e	V	V	\	/	V	V	V	V	V		
		Single command	d to set	PGOC	D, V(TUC	JND	ER VO	LTAGE(I	JV) and		1	-1	
		VOŬT_OVER_VO												
		Format				•		Hn	signed	Ringry				
		Bit Position	_	7		6	5		4		2	1	0	
			1		+			_	-	3		1		
		Access		r		r	r		r	r	r	r/w	r/w	
		Function		Χ		Х	X		X	X	X	PCT_ MSB	PCT_ LSB	
	DOT HOUT SALUT DO LIMIT	Default Valu	10	0		X	X		Х	Χ	Х	0	0	
D7	PCT_VOUT_FAULT_PG_LIMIT	PAGE Command				^	^		^	^	Λ	U	O	
					()					2011	2011		1011	
			r_LS	UV (9	6)	PG		PG		PGH	PGH		(%)	
		SB	В			LO\ (%		HIG (%		HIGH (%)	LOW (%)			
		0 0	0	-16.6	57	-12	.5	-8.3	33	12.5	8.33	16	5.67	
		0 :	1	-12.	5	-8.3	3	-4.1	.7	8.33	4.17	1	2.5	
		1 (0	-29.1	.7	-20.	33	-16.	67	8.33	4.17	1	2.5	
		1	1	-41.6	57	-37.	.5	-33	33	8.33	4.17	1	2.5	
		Llood to cot dolor	14 to tur			n off	mod	uloc ~	c a ratio	of TON	I DICE !	/aluga aa	ın ranga	
		Used to set delay from 0 to 7 and							s a ratio	יוטו וט כ	i_KISE. V	uiues CC	irrunge	
		Format	arc u II	rantiple	011	O11_r			ed Bina	rv _				
D8	SEQUENCE_TON_TOFF_DELAY	Bit Position		7	6			4	3	2	1	0		
סט	SEQUENCE_ION_IOFF_DELAY	Access			r/w	r/		r	r/w	r/w	r/w	r	-	
		Function		r/w r/ TON I			**	- 1			DELAY		-	
		Default Value	٥	0	0	1 (,	0	0	011_DL	0	0	1	
		Deluult Vulue	C	U	U		,	U	U	U	U	U	J	

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Thermal Considerations

Power modules operate in a variety of thermal environments; however, sufficient cooling should always be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel. The test set-up is shown in Figure 42. The preferred airflow direction for the module is in Figure 43.

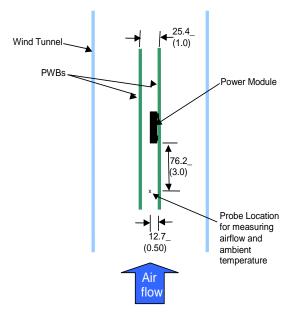


Figure 42. Thermal Test Setup.

The thermal reference point, T_{ref} used in the specifications is shown in Figure 43. For reliable operation, the temperature at this points should not exceed 115°C. The output power of the module should not exceed the rated power of the module (Vo,set x lo,max).

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

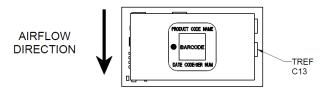


Figure 43. Preferred airflow direction and location of hotspot of the module (Tref).

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Example Application Circuit

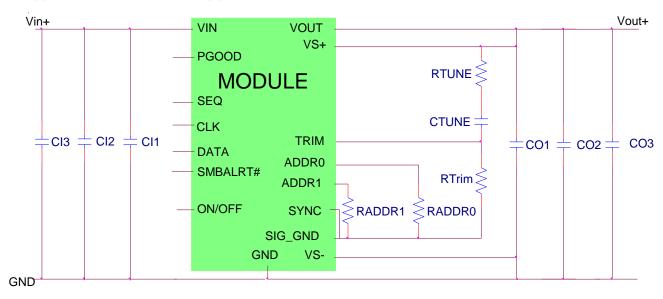
Requirements:

Vin: 12V Vout: 1.8V

lout: 26A max., worst case load transient is from 17.5A to 26A

ΔVout: 1.5% of Vout (27mV) for worst case load transient

Vin, ripple 1.5% of Vin (180mV, p-p)



CII Decoupling caps - $1\times0.047\mu$ F/16V 0402 or 0306ceramic capacitor (e.g. Murata LLL185R71C473MA01) +

1x0.1uF/16V 0402 ceramic cpacitor

CI2 6x22µF/16V ceramic capacitor (e.g. Murata GRM32ER61C226KE20)

CI3 $47\mu F/16V$ bulk electrolytic

CO1 Decoupling cap - $1\times0.047\mu$ F/16V ceramic capacitor (e.g. Murata LLL185R71C473MA01) + $1\times0.1\mu$ F/16V 0402

ceramic cpacitor

CO2 8 x 47uF/6.3V 1210 ceramic capacitor

CO3 4 x 330uF/6V POSCAP

CTune 3300pF ceramic capacitor (can be 1206, 0805 or 0603 size)

RTune 300Ω SMT resistor (can be 1206, 0805 or 0603 size)

RTrim $10k\Omega$ SMT resistor (can be 1206, 0805 or 0603 size, recommended tolerance of 0.1%)

Note: The DATA, CLK and SMBALRT pins do not have any pull-up resistors inside the module. Typically, the SMBus master controller will have the pull-up resistors as well as provide the driving source for these signals.

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

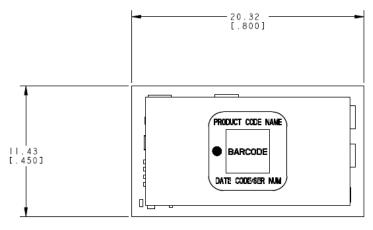
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

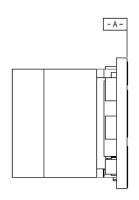
Mechanical Outline

Dimensions are in millimeters and (inches).

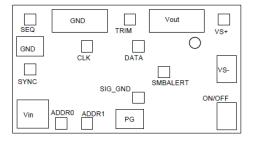
Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)





TOP VIEW

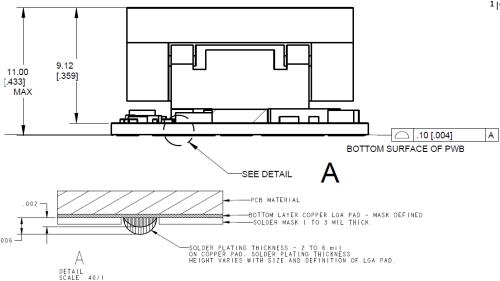


BOTTOM VIEW

SIDE VIEW

PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	10	SYNC ²
2	VIN	11	CLK
3	SEQ	12	DATA
4	GND	13	SMBALERT#
5	TRIM	14	SIG_GND
6	VOUT	15	ADDR1
7	VS+	16	ADDR0
8	VS-	17	INPUT_GND
9	PG		

¹ If unused, connect to SIG_GND



35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

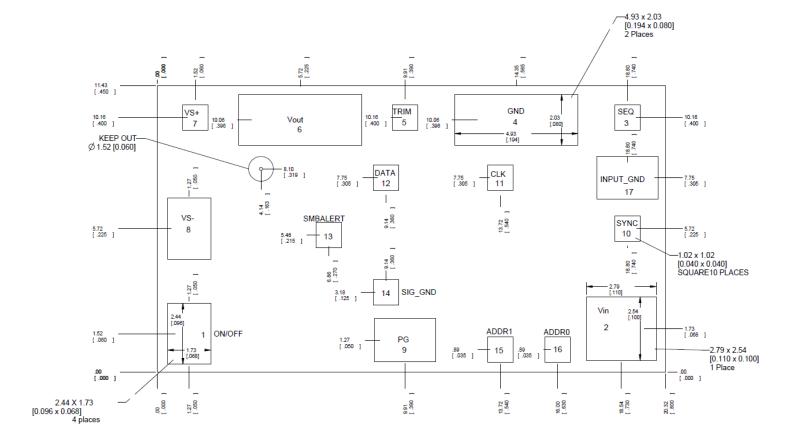
4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Recommended Pad Layout

Dimensions are in millimeters and (inches).

Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)



PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	10	SYNC ²
2	VIN	11	CLK
3	SEQ	12	DATA
4	GND	13	SMBALERT#
5	TRIM	14	SIG_GND
6	VOUT	15	ADDR1
7	VS+	16	ADDR0
8	VS-	17	INPUT_GND
9	PG		·

² If unused, connect to SIG_GND.

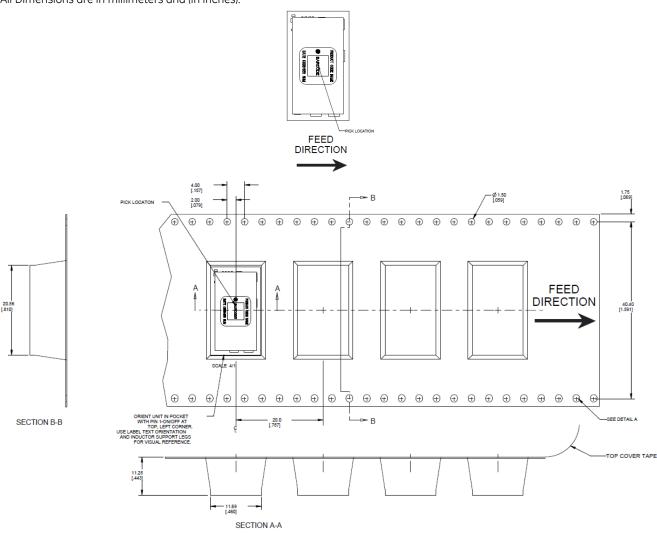
35A Digital MicroDLynxII™: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Packaging Details

The 12V Digital MicroDLynxIITM 35A modules are supplied in tape & reel as standard. Modules are shipped in quantities of 200 modules per reel.

All Dimensions are in millimeters and (in inches).





Reel Dimensions:

 Outside Dimensions:
 330.2 mm (13.00)

 Inside Dimensions:
 177.8 mm (7.00")

 Tape Width:
 44.00 mm (1.732")

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Surface Mount Information

Pick and Place

The 35A Digital MicroDLynxII™ modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

Nozzle Recommendations

The module weight has been kept to a minimum by using open frame construction. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended inside nozzle diameter for reliable operation is 3mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 7 mm.

Bottom Side / First Side Assembly

This module is not recommended for assembly on the bottom side of a customer board. If such an assembly is attempted, components may fall off the module during the second reflow process.

Lead Free Soldering

The modules are lead-free (Pb-free) and RoHS compliant and fully compatible in a Pb-free soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

Pb-free Reflow Profile

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). For questions regarding Land grid array(LGA) soldering, solder volume; please contact GE for special manufacturing process instructions. The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 44. Soldering outside of the recommended profile requires testing to verify results and performance.

MSL Rating

The 35A Digital MicroDLynxII $^{\text{TM}}$ modules have a MSL rating of 2A.

Storage and Handling

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount

Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of $\leq 30^{\circ}$ C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions: $< 40^{\circ}$ C, < 90% relative humidity.

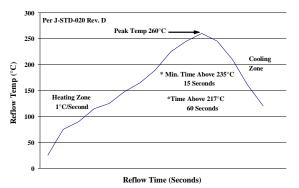


Figure 44. Recommended linear reflow profile using Sn/Ag/Cu solder.

Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to Board Mounted Power Modules: Soldering and Cleaning Application Note (AN04-001).

GF Data Sheet

35A Digital MicroDLynxIITM: Non-Isolated DC-DC Power Modules

4.5Vdc -14.4Vdc input; 0.51Vdc to 3.63Vdc output; 35A Output Current

Ordering Information

Please contact your GE Sales Representative for pricing, availability and optional features.

Table 9. Device Codes

Device Code	Input Voltage Range	Output Voltage	Output Current	On/Off Logic	Sequencing	Comcodes
UJT035A0X3-SRZ	4.5 - 14.4Vdc	0.51 - 3.63Vdc	35A	Negative	Yes	150047126
UJT035A0X43-SRZ	4.5 – 14.4Vdc	0.51 - 3.63Vdc	35A	Positive	Yes	150047127

⁻Z refers to RoHS compliant parts

Table 10. Coding Scheme

Package Identifier	Family	Sequencing Option	Output current	Output voltage	On/Off logic	Remote Sense	Options		ROHS Compliance
U	J	T	035A0	X		3	-SR		Z
P=Pico U=Micro M=Mega G=Giga	J=DLynx II Digital K = DLynxII Analog.	T=with EZ Sequence X=without sequencing	35A	X = programm able output	4 = positive No entry = negative	3 = Remote Sense	S = Surface Mount R = Tape & Reel	No entry = Standard D = 105°C operating ambient, 40G operating shock as per MIL Std 810F	Z = ROHS6

GE Digital Non-Isolated DC-DC products use technology licensed from Power-One, protected by US patents: US20040246754, US2004090219A1, US2004093533A1, US2004123164A1,

US2004123167A1, US2004179780A1, US2004179382A1, US20050200344, US20050223252, US2005289373A1, US20060061214, US2006015616A1, US2006017445, US2006006123167A1, US2006178780A1, US2006006178780A1, US2006006178145, US2006006178145, US2006006178780A1, US2006006178145, US2006006178780A1, US2006006178145, US2006006178780A1, US2006006178145, US2006006178445, US200600617845, US2006006178145, US200600617845, US20060061 W004062061 A1, W004062062A1, W004070780A3, W004084390A3, W004084391A3, W005079227A3, W005081771A3, W006019569A3, W02007001584A3, W02007094935A3

Contact Us

For more information, call us at

USA/Canada:

+1 888 546 3243, or +1 972 244 9288

Asia-Pacific:

+86.021.54279977*808

Europe, Middle-East and Africa:

+49.89.878067-280



www.gecriticalpower.com

GE Critical Power reserves the right to make changes to the product(s) or information contained herein without notice, and no liability is assumed as a result of their use or application. No rights under any patent accompany the sale of any such product(s) or information.